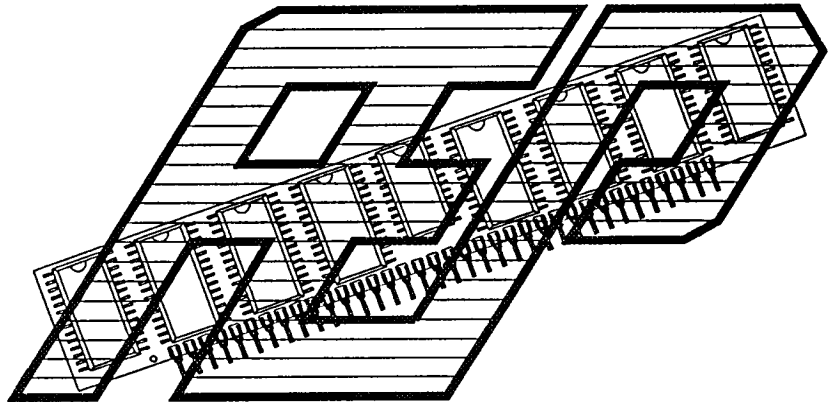


- >> 524,288 x 8 Organization
- >> Double sided to maximize bit density
- >> On board 1-of-16 Decoder
- >> Completely Static operation
- >> TTL compatible
- >> Low power, battery back-up operation capability
- >> Uses single +5V power supply
- >> Super Low Power version available



512 KILOBYTE STATIC RAM MODULE

DESCRIPTION:

The AEPSX512K8 is a high density 512 Kilo-word by 8 bit static random access memory module in a 36 pin single-inline-package format. Physically it consists of an FR4 PC material substrate mounted with sixteen 32K x 8 SOP (small outline package) ICs, the 1-of-16 decoder, four 0.1 microfarad decoupling capacitors, and 36 edge-clip I/O pins.

The module can use any of the 32K x 8 SRAMs made by any of a large number of manufacturers in both Mix-MOS and CMOS technologies. A wide range of access speeds are available. The decoder normally used is the 74HCT154. Other decoder choices available are the 74F154, the 74LS154, and the fully CMOS version 74HC154.

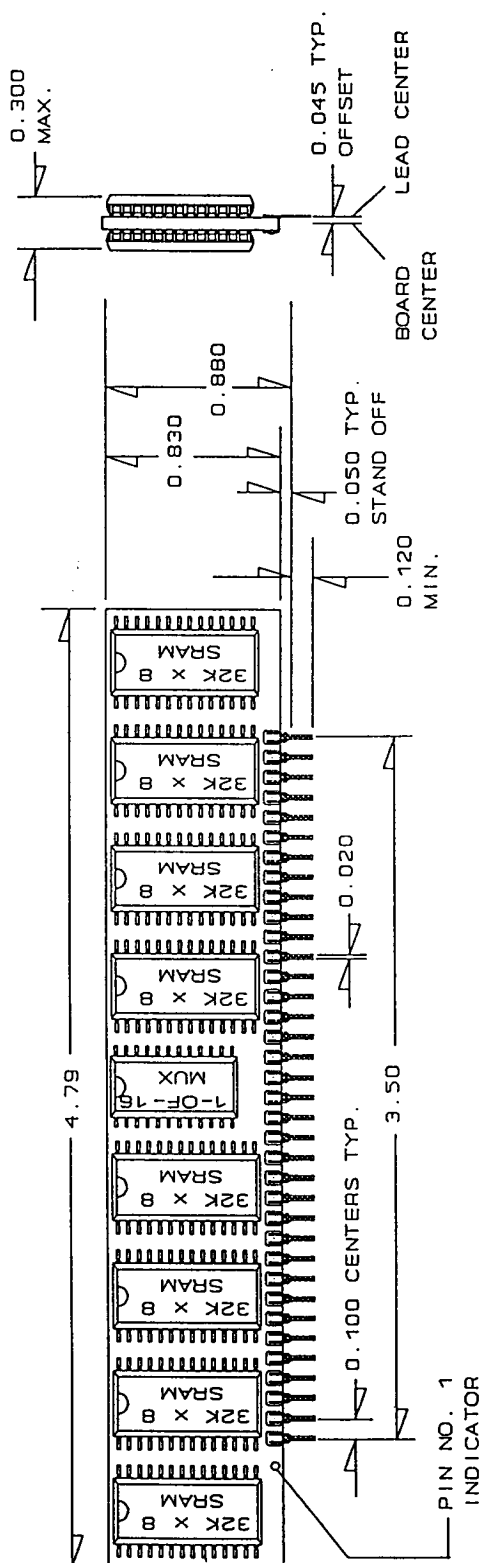
Performance specifications and electrical characteristics are determined by the IC devices used. A typical memory component on the module will draw 100uA (max.) in standby and 70mA (max.) during access (for standard low power devices, super low power use 2uA and 8mA typically).

Mechanical dimensions are 0.88 in. high by 4.79 in. long by 0.30 in. wide. The module is available with either vertical or 90 degree (horizontal) lead pins. The latter allows the module to be mounted on its side which gives a low 0.325 stand-off height.

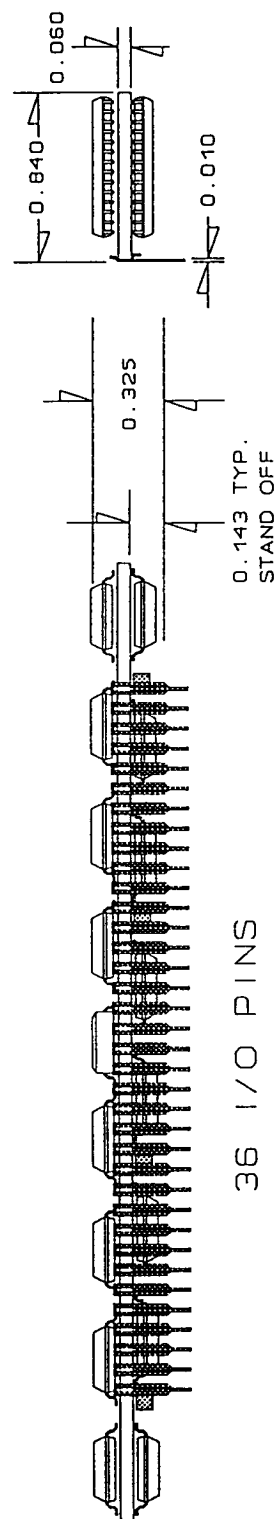


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FRONT AND SIDE VIEWS
(SHOWING VERTICAL MOUNTING LEADS OPTION)



BOTTOM AND SIDE VIEWS
(SHOWING HORIZONTAL MOUNTING LEADS OPTION)

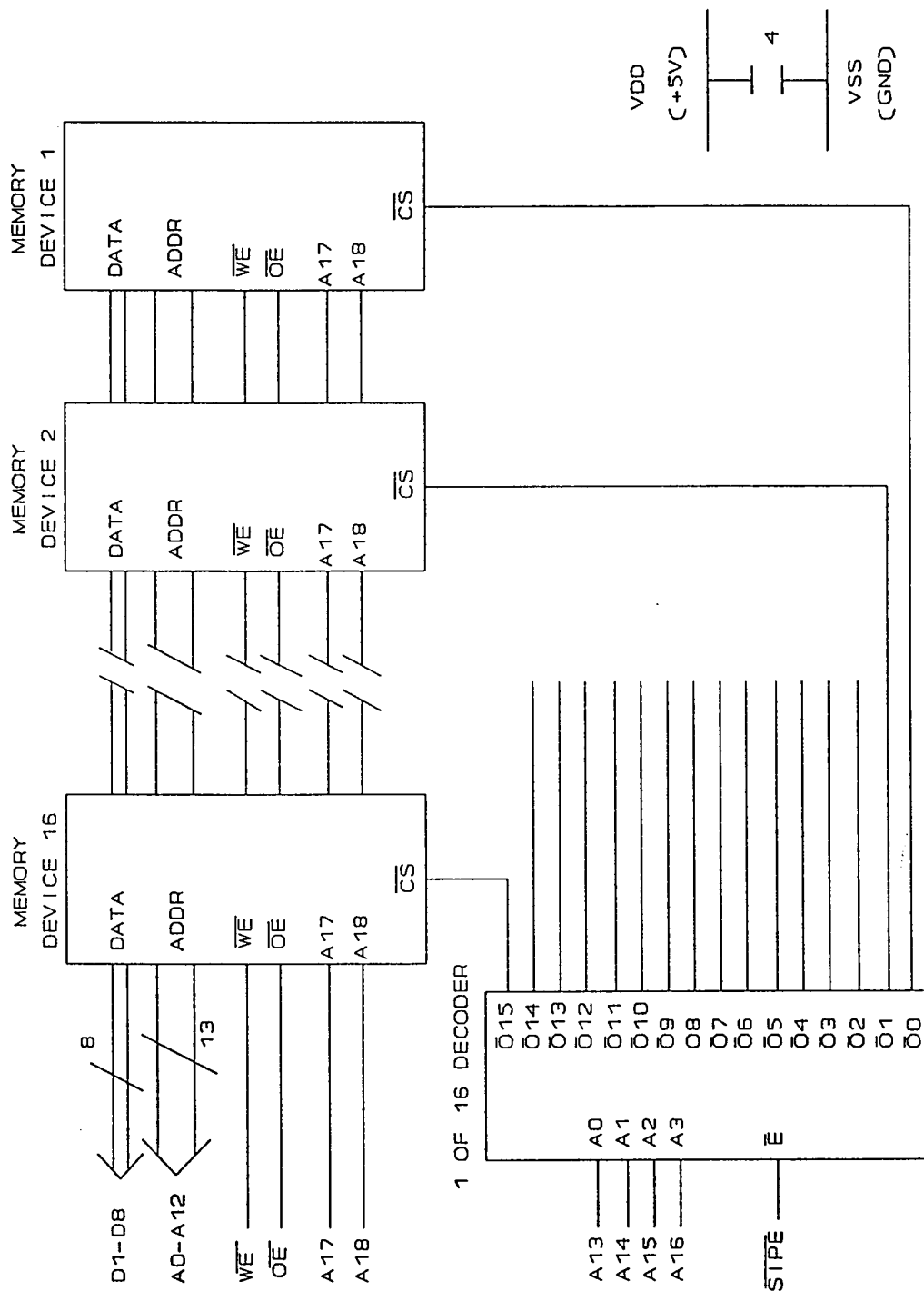
DIMENSIONS IN INCHES
TOLERANCE: ± 0.010
UNLESS SPECIFIED
DRAWING DATE: 4-2-89



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512K x 8 STATIC RAM MODULE
FUNCTIONAL DIAGRAM

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512K x 8 STATIC RAM MODULE SIP PIN-OUT CONFIGURATION

1	N/C		
2	Vcc		
3	WE	A ₀ - A ₁₈	ADDRESS INPUTS
4	I/O ₃	I/O ₁ - I/O ₈	DATA LINES
5	I/O ₄		
6	I/O ₁		
7	A ₁	WE	WRITE ENABLE*
8	A ₂		
9	A ₃	SIP E	SIP ENABLE*
10	A ₄		
11	Vss	OE	OUTPUT ENABLE*
12	I/O ₆		
13	A ₁₀	Vcc	POWER (+5V)
14	A ₁₁		
15	A ₅	Vss	GROUND
16	A ₁₃		
17	A ₁₄	N/C	NO CONNECT
18	N/C		
19	SIP E		*ACTIVE LOW
20	A ₁₅		
21	A ₁₆		
22	A ₁₂	128K x 8 version notes: pin 23 is a NO CONNECT. pin 34 is a CHIP SELECT (active low).	
23	A ₁₈		
24	A ₆		
25	I/O ₂	High address notes: Address inputs A13 to A16 are connected to the decoder on both the 128K and the 512K versions. If compatibility between the two versions is not a concern, then it is recommended making these the highest order address lines when using the 512K module exclusively.	
26	Vss		
27	A ₀		
28	A ₇		
29	A ₈		
30	A ₉		
31	I/O ₈		
32	I/O ₅		
33	I/O ₇		
34	A ₁₇		
35	Vcc		
36	OE		



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PART NUMBERING CHART

Standard 512K x 8	Vertical lead pins	Horizontal lead pins
35ns SRAM ICs	AEPSS512K8-35	AEP5H512K8-35
55ns SRAM ICs	AEPSS512K8-55	AEP5H512K8-55
70ns SRAM ICs	AEPSS512K8-70	AEP5H512K8-70
85ns SRAM ICs	AEPSS512K8-85	AEP5H512K8-85
100ns SRAM ICs	AEPSS512K8-10	AEP5H512K8-10
120ns SRAM ICs	AEPSS512K8-12	AEP5H512K8-12
Super Low Power		
100ns SRAM ICs	AEPSS512K8-10SL	AEP5H512K8-10SL
120ns SRAM ICs	AEPSS512K8-12SL	AEP5H512K8-12SL

Decoder notes:

The standard decoder used with 100ns and slower SRAMs is the HCT154. AEP may substitute the F154 or the LS154 if these are more readily available. The F154 decoder is standard with SRAMs faster than 100ns. On Super Low Power versions of the module the CMOS compatible HC154 is standard. Specific decoders may be ordered with any speed or version of the module by adding -HCT, -HC, -F, or -LS to the end of the part number.

The decoder does effect the memory access speed of the module. The HCT154 can add 35ns in worst case. The F154 adds only 10ns worst case but draws more power. Consult the Signetics data book for details.

Memory notes:

Memory access speeds specified in the part numbers are maximums for the SRAM ICs used. AEP reserves the right to use faster rated devices unless requested not to. As an example, 100ns parts may be substituted for 120ns parts depending on stocks on hand.

Due to the rapidly progressing nature of SRAM development, devices with access speeds other than those listed are likely to be available also. Check with AEP.

Vendor notes:

The IC device specification information which may be included is typical and does not limit AEP to that vendor. The actual devices used will be equivalent depending on price, availability, and customer requirements. AEP will gladly use or exclude particular manufacturers upon request. However, this may affect module price.

Disclaimers:

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